# NSN 5961-01-095-8471

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-095-8471

Inclosure Material:

Metal

**Overall Length:** 

0.340 inches

# **Overall Diameter:**

0.620 inches

# Mounting Facility Quantity:

2

#### Internal Configuration:

Junction contact

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-66

Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open

# **Current Rating Per Characteristic:**

4.00 amperes source cutoff current

# Power Rating Per Characteristic:

20.0 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

### Unit Of Measure:

---

Demilitarization:

No

Fiig:

A110a0